Characteristics of a PV module

Manufacturer, model : **Trina Solar, TSM-485DE18M(II)**

Availability : Prod. Since 2020

Data source : UL 2020

STC power (manufacturer)	**Pnom**	**485**	**Wp**	**Technology**		**Si-mono**	
Module size (W x L)		1.098 x 2.176	m²	Rough module area	Amodule	2.39	m²
Number of cells		2 x 75		Sensitive area (cells)	Acells	2.21	m²

Specifications for the model (manufacturer or measurement data)

Reference temperature	TRef	25	°C	Reference irradiance	GRef	1000	W/m²
Open circuit voltage	Voc	51.1	V	Short-circuit current	Isc	12.07	A
Max. power point voltage	Vmpp	42.2	V	Max. power point current	Impp	11.49	A
=> maximum power	Pmpp	484.9	W	Isc temperature coefficient	muIsc	6.2	mA/°C

One-diode model parameters

Shunt resistance	Rshunt	300	ohm	Diode saturation current	IoRef	0.015	nA
Serie resistance	Rserie	0.24	ohm	Voc temp. coefficient	MuVoc	-156	mV/°C
				Diode quality factor	Gamma	0.97	
Specified Pmax temper. coeff.	muPMaxR	-0.36	%/°C	Diode factor temper. coeff.	muGamma	-0.001	1/°C

Reverse Bias Parameters, for use in behaviour of PV arrays under partial shadings or mismatch

Reverse characteristics (dark)	BRev	3.20	mA/V²	(quadratic factor (per cell))			
Number of by-pass diodes per module		3		Direct voltage of by-pass diodes		-0.7	V

Model results for standard conditions (STC: T=25°C, G=1000 W/m², AM=1.5)

Max. power point voltage	Vmpp	42.5	V	Max. power point current	Impp	11.42	A
Maximum power	Pmpp	485.2	Wc	Power temper. coefficient	muPmpp	-0.35	%/°C
Efficiency(/ Module area)	Eff_mod	20.3	%	Fill factor	FF	0.787	
Efficiency(/ Cells area)	Eff_cells	22.0	%				

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